

Vishay Siliconix

N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A)		
30	0.012 at V _{GS} = 10 V	12.4		
	0.020 at V _{GS} = 4.5 V	9.6		

FEATURES

Halogen-free According to IEC 61249-2-21
Available

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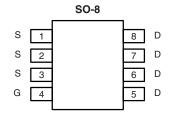
N-Channel MOSFET

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- TrenchFET[®] Power MOSFETs
- High Efficiency PWM Optimized
- 100 % R_g Tested
- 100 % UIS Tested





Top View



Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	30		V	
Gate-Source Voltage		V _{GS}	± 20			
	T _A = 25 °C	1	12.4	8.8		
Continuous Drain Current $(T_J = 150 \ ^{\circ}C)^a$	T _A = 70 °C	- I _D	9.9	7.0		
Pulsed Drain Current		I _{DM}	± 50		А	
Continuous Source Current (Diode Conduction) ^a		۱ _S	2.60	1.3		
Avalanche Current		I _{AS}	20			
Single-Pulse Avalanche Energy	L = 0.1 mH	E _{AS}	20		mJ	
	T _A = 25 °C	– P _D	3.1	1.6	w	
Maximum Power Dissipation ^a	T _A = 70 °C		2.0	1.0	~~~	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
	t ≤ 10 s	R _{thJA}	34	40	°C/W
Maximum Junction-to-Ambient (MOSFET) ^a	Steady State		70	80	
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	17	20	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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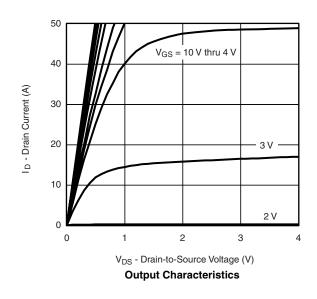
MOSFET SPECIFICATIONS $T_J = 25 \text{ °C}$, unless otherwise noted							
Parameter	Symbol Test Conditions		Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	0.80			V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V$, $V_{GS} = \pm 20 V$			± 100	nA	
Zero Gate Voltage Drain Current	1	$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$ $V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 70 \text{ °C}$			1	μA	
	I _{DSS}				5		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	50			А	
Drain-Source On-State Resistance ^a	D	V _{GS} = 10 V, I _D = 12.4 A		0.010	0.012	Ω	
	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 9.6 \text{ A}$		0.016 0.020			
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 12.4 A		27		S	
Diode Forward Voltage ^a	V _{SD}	$I_{\rm S}$ = 2.6 A, $V_{\rm GS}$ = 0 V		0.75	1.2	V	
Dynamic ^b				•	•		
Total Gate Charge	Qg			8.7	10.5	nC	
Gate-Source Charge	Q _{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 5.0 \text{ V}, I_{D} = 12.4 \text{ A}$		2.4			
Gate-Drain Charge	Q _{gd}			3.5			
Gate Resistance	R _g		0.5	1.1	1.9	Ω	
Turn-On Delay Time	t _{d(on)}			10	20	ns	
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω		11	20		
Turn-Off Delay Time	t _{d(off)}	${\rm I}_{\rm D}\cong$ 1 A, ${\rm V}_{\rm GEN}$ = 10 V, ${\rm R}_{\rm g}$ = 6 Ω		24	50		
Fall Time	t _f			10	20		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2.6 A, dl/dt = 100 A/μs		50	75		
Reverse Recovery Charge	Q _{rr}	$r_{\rm F} = 2.0$ Å, di/dt = 100 Å/µS		38		nC	

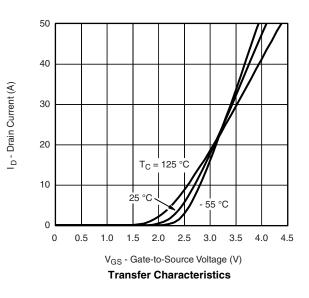
Notes:

a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





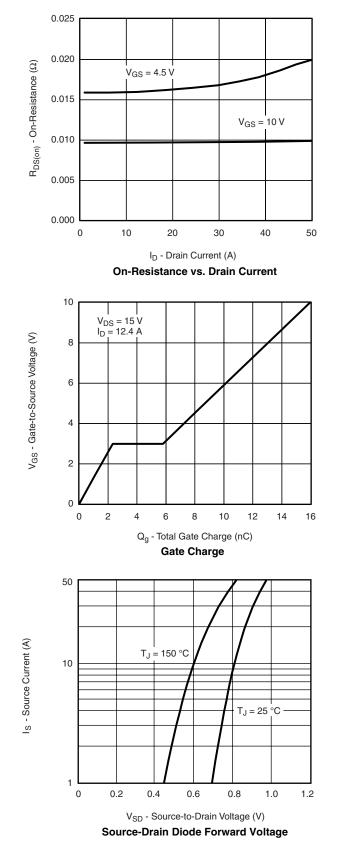
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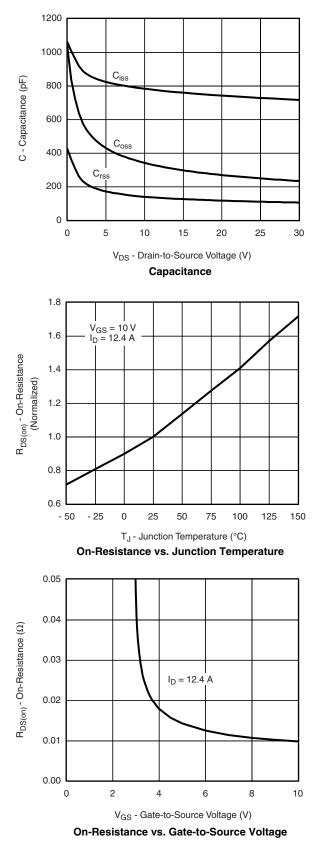


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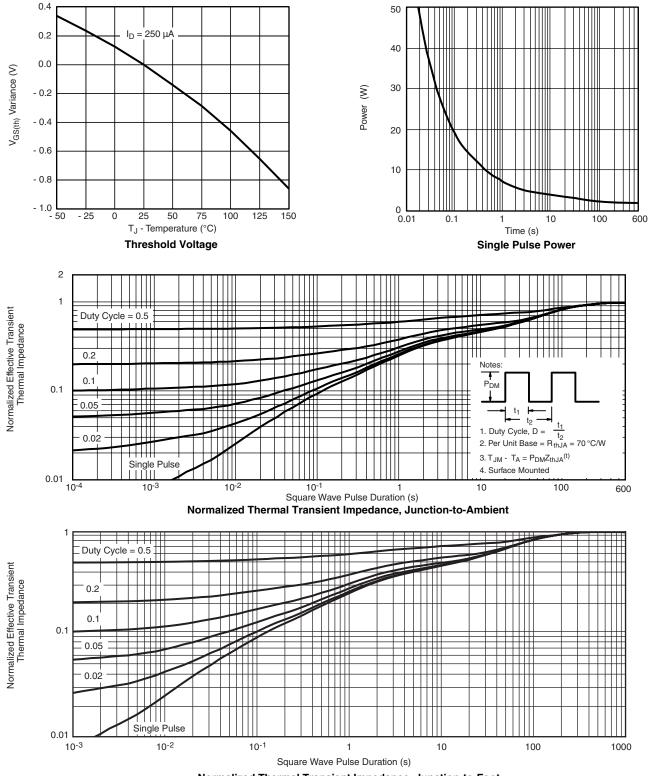
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted







TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71407.



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